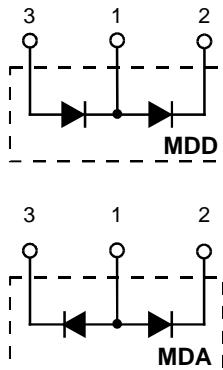


Diode Modules

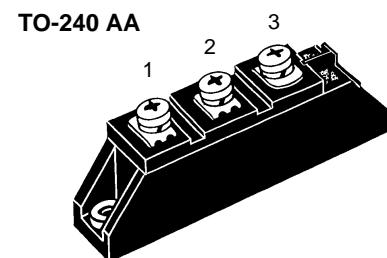
| V_{RSM} | V_{RRM} | Type |
|-----------|-----------|---------------|
| V | V | |
| 900 | 800 | MDD 72-08N1 B |
| 1300 | 1200 | MDD 72-12N1 B |
| 1500 | 1400 | MDD 72-14N1 B |
| 1700 | 1600 | MDD 72-16N1 B |
| 1900 | 1800 | MDD 72-18N1 B |
| | | MDA 72-08N1 B |
| | | --- |
| | | MDA 72-14N1 B |
| | | MDA 72-16N1 B |
| | | --- |



$$I_{FRMS} = 2 \times 180 \text{ A}$$

$$I_{FAVM} = 2 \times 113 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$



| Symbol | Test Conditions | Maximum Ratings | |
|---------------|--|-----------------------|----------------------|
| I_{FRMS} | $T_{VJ} = T_{VJM}$ | 180 | A |
| I_{FAVM} | $T_c = 92^\circ\text{C}$; 180° sine | 113 | A |
| | $T_c = 100^\circ\text{C}$; 180° sine | 99 | A |
| I_{FSM} | $T_{VJ} = 45^\circ\text{C}$; $V_R = 0$ | 1700 | A |
| | $t = 10 \text{ ms}$ (50 Hz), sine | 1950 | A |
| | $t = 8.3 \text{ ms}$ (60 Hz), sine | 1540 | A |
| | $T_{VJ} = T_{VJM}$; $V_R = 0$ | 1800 | A |
| | $t = 10 \text{ ms}$ (50 Hz), sine | 14 450 | A^2s |
| | $t = 8.3 \text{ ms}$ (60 Hz), sine | 15 700 | A^2s |
| $\int i^2 dt$ | $T_{VJ} = T_{VJM}$; $V_R = 0$ | 11 850 | A^2s |
| | $t = 10 \text{ ms}$ (50 Hz), sine | 13 400 | A^2s |
| T_{VJ} | | -40...+150 | $^\circ\text{C}$ |
| T_{VJM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -40...+125 | $^\circ\text{C}$ |
| V_{ISOL} | 50/60 Hz, RMS | 3000 | $\text{V}\sim$ |
| | $I_{ISOL} \leq 1 \text{ mA}$ | 3600 | $\text{V}\sim$ |
| M_d | Mounting torque (M5) | 2.5-4/22-35 | Nm/lb.in. |
| | Terminal connection torque (M5) | 2.5-4/22-35 | Nm/lb.in. |
| Weight | Typical including screws | 90 | g |
| Symbol | Test Conditions | Characteristic Values | |
| I_R | $T_{VJ} = T_{VJM}$; $V_R = V_{RRM}$ | 15 | mA |
| V_F | $I_F = 300 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$ | 1.6 | V |
| V_{T0} | For power-loss calculations only | 0.8 | V |
| r_T | $T_{VJ} = T_{VJM}$ | 2.3 | $\text{m}\Omega$ |
| Q_S | $T_{VJ} = 125^\circ\text{C}$; $I_F = 50 \text{ A}$, $-di/dt = 3 \text{ A}/\mu\text{s}$ | 170 | μC |
| I_{RM} | | 45 | A |
| R_{thJC} | per diode; DC current | 0.35 | K/W |
| | per module | 0.175 | K/W |
| R_{thJK} | per diode; DC current | 0.55 | K/W |
| | per module | 0.275 | K/W |
| d_s | Creepage distance on surface | 12.7 | mm |
| d_A | Strike distance through air | 9.6 | mm |
| a | Maximum allowable acceleration | 50 | m/s^2 |

Data according to IEC 60747 and refer to a single diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions

Features

- International standard package JEDEC TO-240 AA
- Direct copper bonded Al_2O_3 -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 $\text{V}\sim$
- UL registered, E 72873

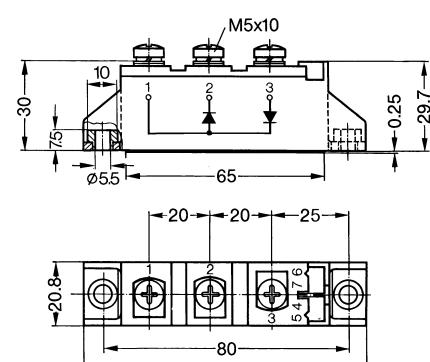
Applications

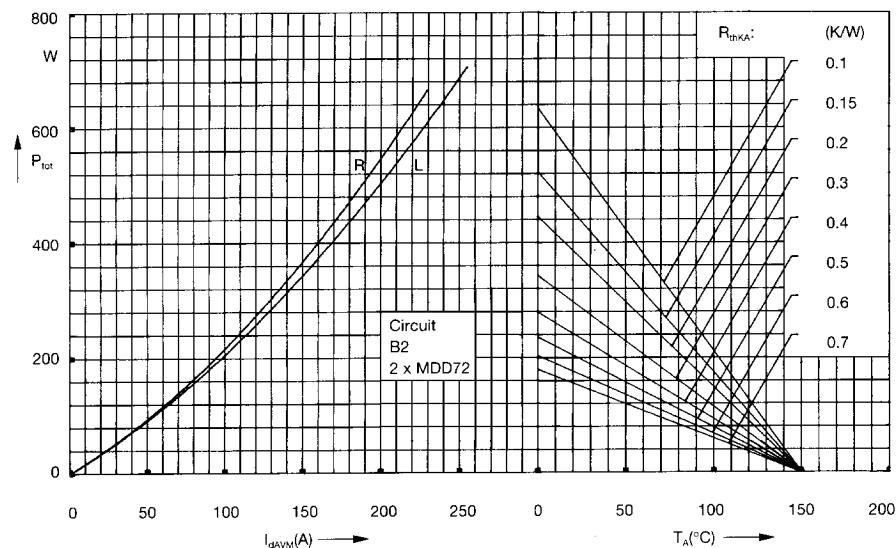
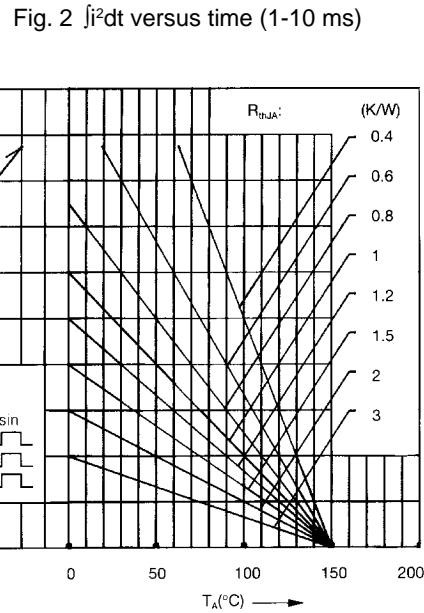
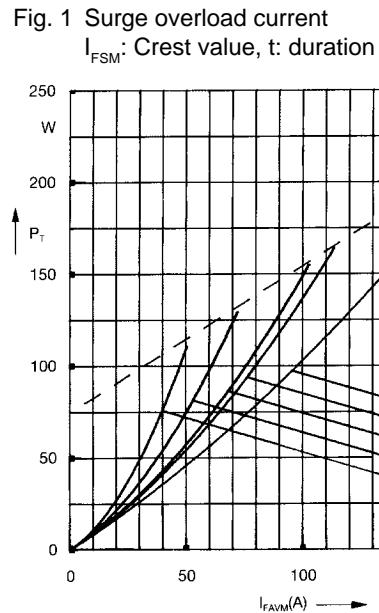
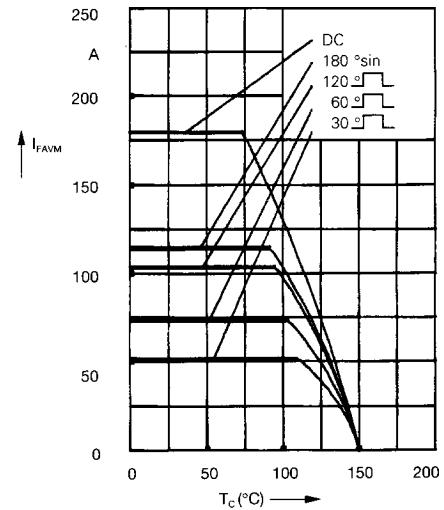
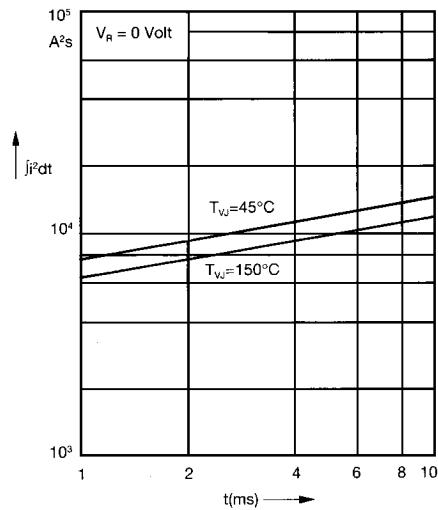
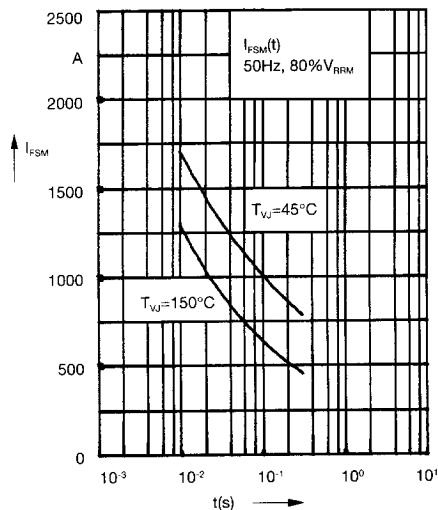
- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")





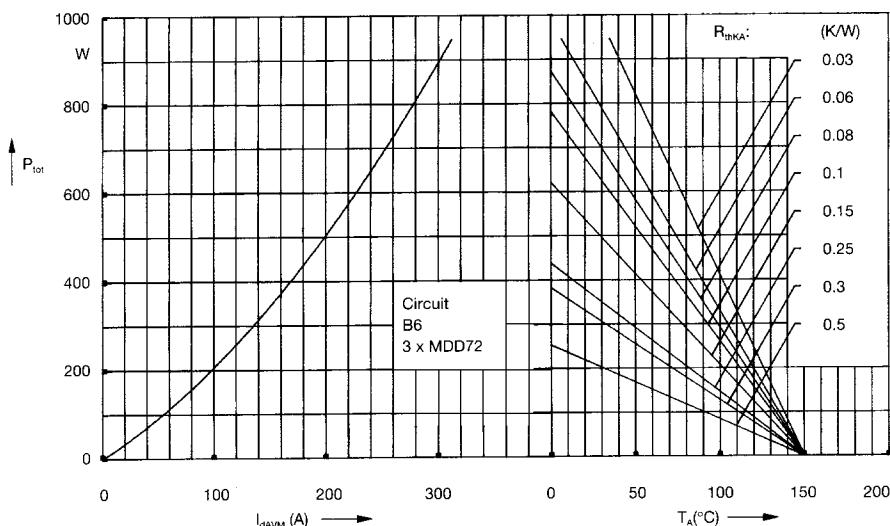


Fig. 5 Three phase rectifier bridge:
Power dissipation versus direct
output current and ambient
temperature

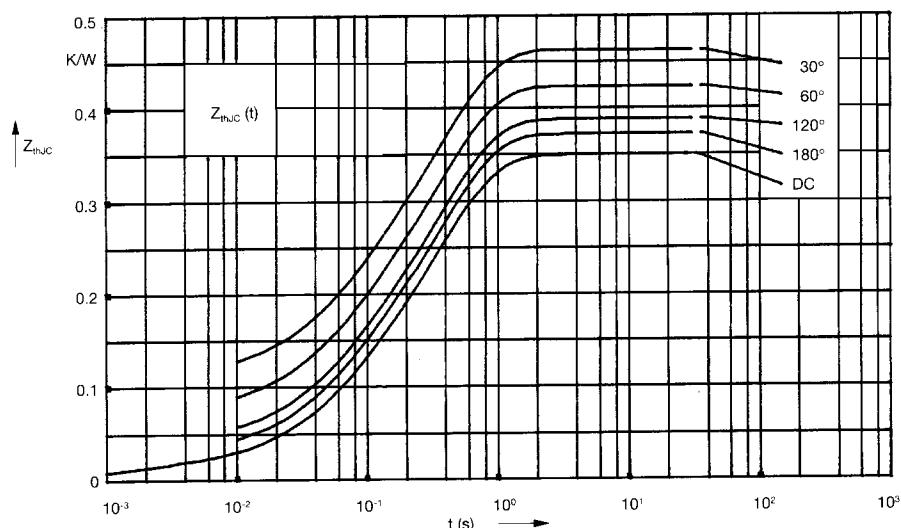


Fig. 6 Transient thermal impedance
junction to case (per diode)

| d | R_{thJC} (K/W) |
|------|------------------|
| DC | 0.35 |
| 180° | 0.37 |
| 120° | 0.39 |
| 60° | 0.43 |
| 30° | 0.47 |

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|-----|-----------------|-----------|
| 1 | 0.013 | 0.0014 |
| 2 | 0.072 | 0.062 |
| 3 | 0.265 | 0.375 |

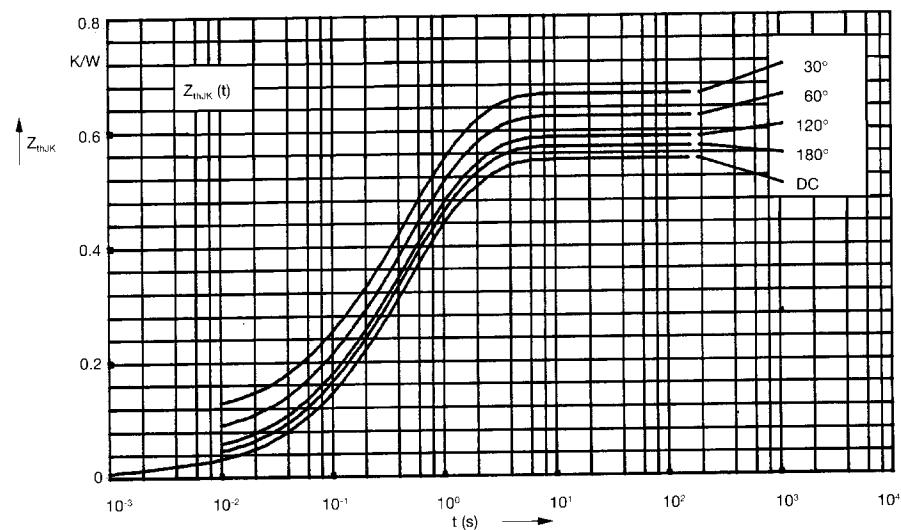


Fig. 7 Transient thermal impedance
junction to heatsink (per diode)

| d | R_{thJK} (K/W) |
|------|------------------|
| DC | 0.55 |
| 180° | 0.57 |
| 120° | 0.59 |
| 60° | 0.63 |
| 30° | 0.67 |

Constants for Z_{thJK} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|-----|-----------------|-----------|
| 1 | 0.013 | 0.0014 |
| 2 | 0.072 | 0.062 |
| 3 | 0.265 | 0.375 |
| 4 | 0.2 | 1.32 |